MMBF4391L, MMBF4392L, MMBF4393L

JFET Switching Transistors N-Channel

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	30	Vdc
Drain-Gate Voltage	V _{DG}	30	Vdc
Gate-Source Voltage	V _{GS}	30	Vdc
Forward Gate Current	I _{G(f)}	50	mAdc

THERMAL CHARACTERISTICS

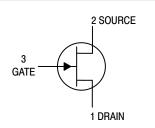
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR- 5 Board (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in. ON

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MARKING DIAGRAM



XXX = Specific Device Code M = Date Code* = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

MARKING & ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 2 of this data sheet.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	·			
Gate-Source Breakdown Voltage $(I_G = 1.0 \ \mu Adc, \ V_{DS} = 0)$	V _{(BR)GSS}	30	_	Vdc
Gate Reverse Current (V_{GS} = 15 Vdc, V_{DS} = 0, T_A = 25°C) (V_{GS} = 15 Vdc, V_{DS} = 0, T_A = 100°C)	I _{GSS}		1.0 0.20	nAdc μAdc
$ \begin{array}{l} \mbox{Gate-Source Cutoff Voltage} \\ \mbox{(V}_{DS} = 15 \mbox{ Vdc}, \mbox{I}_{D} = 10 \mbox{ nAdc}) \\ \mbox{MMBF4391LT1} \\ \mbox{MMBF4392LT1} \\ \mbox{MMBF4393LT1} \end{array} $	V _{GS(off)}	-4.0 -2.0 -0.5	-10 -5.0 -3.0	Vdc
$\begin{array}{l} \mbox{Off-State Drain Current} \\ (V_{DS} = 15 \mbox{ Vdc}, \mbox{ V}_{GS} = -12 \mbox{ Vdc}) \\ (V_{DS} = 15 \mbox{ Vdc}, \mbox{ V}_{GS} = -12 \mbox{ Vdc}, \mbox{ T}_{A} = 100^{\circ}\mbox{C}) \end{array}$	I _{D(off)}		1.0 1.0	nAdc μAdc
ON CHARACTERISTICS				
$\label{eq:constraint} \begin{array}{l} \mbox{Zero-Gate-Voltage Drain Current} \\ (V_{DS} = 15 \mbox{ Vdc}, V_{GS} = 0) \\ \mbox{MMBF4391LT1} \\ \mbox{MMBF4392LT1} \\ \mbox{MMBF4393LT1} \end{array}$	IDSS	50 25 5.0	150 75 30	mAdc
$ \begin{array}{l} \mbox{Drain-Source On-Voltage} \\ (I_D = 12 \mbox{ mAdc}, V_{GS} = 0) \\ \mbox{ MMBF4391LT1} \\ (I_D = 6.0 \mbox{ mAdc}, V_{GS} = 0) \\ \mbox{ MMBF4392LT1} \\ (I_D = 3.0 \mbox{ mAdc}, V_{GS} = 0) \\ \mbox{ MMBF4393LT1} \end{array} $	V _{DS(on)}	- - -	0.4 0.4 0.4	Vdc
$ \begin{array}{l} \text{Static Drain-Source On-Resistance} \\ (I_D = 1.0 \text{ mAdc}, \text{V}_{GS} = 0) \\ \text{MMBF4391LT1} \\ \text{MMBF4392LT1} \\ \text{MMBF4393LT1} \end{array} $	r _{DS(on)}	- -	30 60 100	Ω

SMALL-SIGNAL CHARACTERISTICS

Input Capacitance $(V_{DS} = 0 \text{ Vdc}, V_{GS} = -15 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{iss}	_	14	pF
Reverse Transfer Capacitance $(V_{DS} = 0 \text{ Vdc}, V_{GS} = -12 \text{ Vdc}, f = 1.0 \text{ MHz})$	C _{rss}	-	3.5	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MMBF4391LT1G	6J		
SMMBF4391LT1G*	6J		
MMBF4392LT1G	6K	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBF4393LT1G	M6G		
SMMBF4393LT1G*	M6G		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS

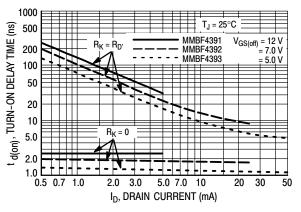


Figure 1. Turn-On Delay Time

1000

500

200

100

50

20

10

5.0

2.0

1.0

t_{d(off)}, TURN-OFF DELAY TIME (ns)

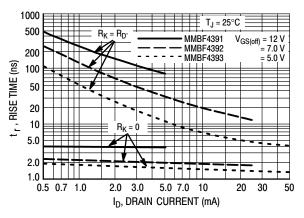


Figure 2. Rise Time

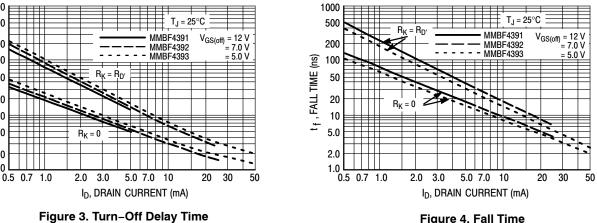


Figure 4. Fall Time

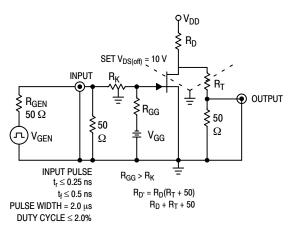


Figure 5. Switching Time Test Circuit

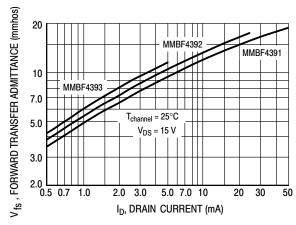


Figure 6. Typical Forward Transfer Admittance

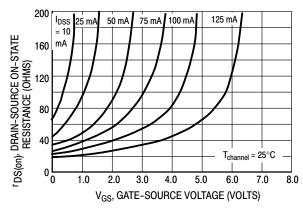


Figure 8. Effect of Gate-Source Voltage on Drain-Source Resistance

NOTE 1

The switching characteristics shown above were measured using a test circuit similar to Figure 5. At the beginning of the switching interval, the gate voltage is at Gate Supply Voltage ($-V_{GG}$). The Drain–Source Voltage (V_{DS}) is slightly lower than Drain Supply Voltage (V_{DD}) due to the voltage divider. Thus Reverse Transfer Capacitance (C_{rss}) of Gate–Drain Capacitance (C_{gd}) is charged to $V_{GG} + V_{DS}$.

During the turn–on interval, Gate–Source Capacitance (C_{gs}) discharges through the series combination of R_{Gen} and R_K . C_{gd} must discharge to $V_{DS(on)}$ through R_G and R_K in series with the parallel combination of effective load impedance (R'_D) and Drain–Source Resistance (r_{DS}). During the turn–off, this charge flow is reversed.

Predicting turn–on time is somewhat difficult as the channel resistance r_{DS} is a function of the gate–source voltage. While C_{gs} discharges, V_{GS} approaches zero and r_{DS} decreases. Since C_{gd} discharges through r_{DS} , turn–on time is non–linear. During turn–off, the situation is reversed with r_{DS} increasing as C_{gd} charges.

The above switching curves show two impedance conditions; 1) R_K is equal to $R_{D'}$ which simulates the switching behavior of cascaded stages where the driving source impedance is normally the load impedance of the previous stage, and 2) $R_K = 0$ (low impedance) the driving source impedance is that of the generator.

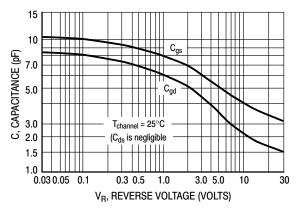


Figure 7. Typical Capacitance

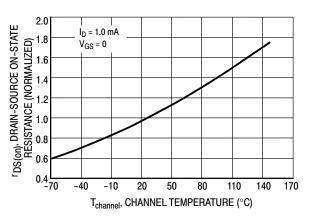
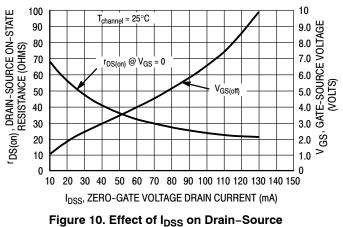


Figure 9. Effect of Temperature on Drain–Source On–State Resistance



Resistance and Gate-Source Voltage

NOTE 2

The Zero–Gate–Voltage Drain Current (I_{DSS}) is the principle determinant of other J–FET characteristics. Figure 10 shows the relationship of Gate–Source Off Voltage ($V_{GS(off)}$) and Drain–Source On Resistance ($r_{DS(on)}$) to I_{DSS} . Most of the devices will be within ±10% of the values shown in Figure 10. This data will be useful in predicting the characteristic variations for a given part number.

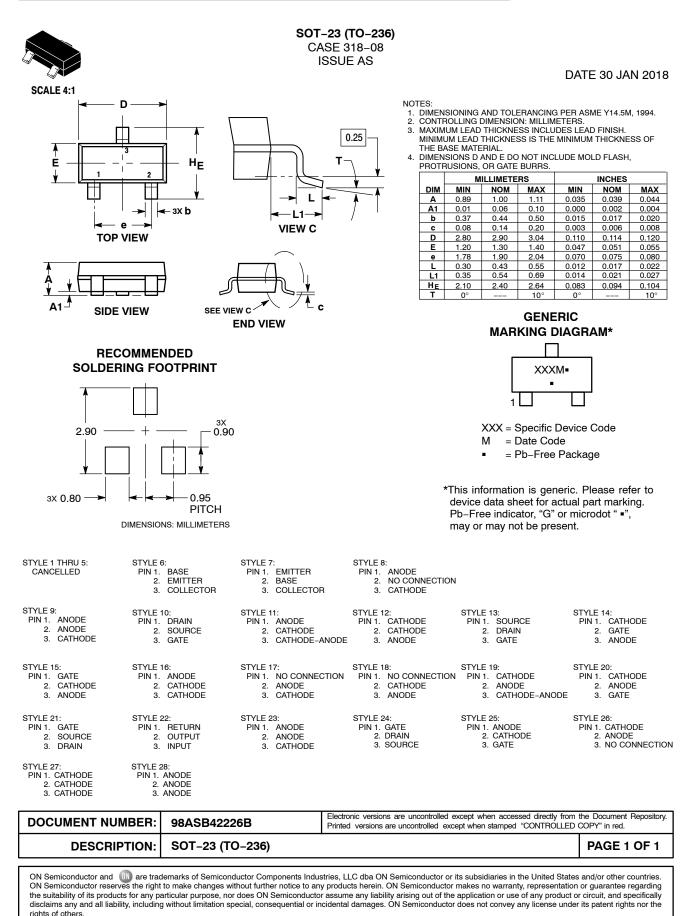
For example:

Unknown

r_{DS(on)} and V_{GS} range for an MMBF4392

The electrical characteristics table indicates that an MMBF4392 has an I_{DSS} range of 25 to 75 mA. Figure 10 shows $r_{DS(on)} = 52 \Omega$ for I_{DSS} = 25 mA and 30 Ω for I_{DSS} = 75 mA. The corresponding V_{GS} values are 2.2 V and 4.8 V.





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